TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

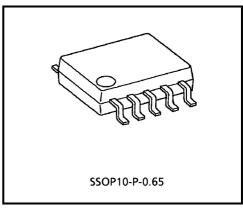
TA2018FN

DC / DC Converter For Electric Tuning (1.5V USE)

The TA2018FN is a DC / DC converter IC which is developed for biasing variable capacitance diodes of tuner system. It is especially suitable for supplying high voltage (about 14.3V) for digital tuning (FM / TV / AM) system at low power operation.

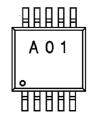
Features

- Few external parts.
- Excellent spurious radiation by oscillation of sine wave.
- Output voltage: Vo = 14.3V (typ.)
- Excellent regulatory capability of output voltage against fluctuation of supply voltage, and of ambient temperature.
- Built-in constant current source, it is suitable for digital
- tuning system. (ICTL can be controlled by RCTL)
- Built-in power switch.
- Low supply current (VCC = 1.2V, Ta = 25°C, IO = 30 μ A) ICC = 2.1mA (typ.)
- Operating supply voltage range (Ta = 25°C) V_{CC} (opr) = 0.9~4V

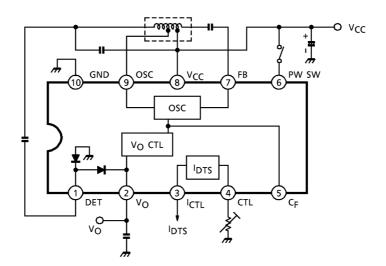


Weight: 0.04g (typ.)

Marking



Block Diagram



Terminal ExplanationTerminal Voltage: Typical Terminal Voltage with Test Circuit (V_{CC} = 1.2V, Ta = 25°C)

	erminal	Function	Internal Circuit	Terminal
No.	Name	1 dilottori	internal Official	Voltage (V)
1	DET	Boosted output		_
2	V _O	(voltage double rectifier)		14.3
5	C _F	Don't connect any external parts with this terminal	DC FEED \$ 1kΩ BACK	0.4
3	Ість	Constant current source V _O supplies this circuit with power	6kΩ 5 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7	_
4	CTL	source. (For digital tuning)	2 4 3 I _{DTS}	_
6	PW SW	Power on / off switch V _{CC} : Power on OPEN / GND: Power off	ν _{CC} 618kΩ ν _{CC}	_
7	FB	Hartley type oscillator	C2 + 1	0.7
8	V _{CC}	$f_{OSC} = \frac{1}{2\pi \sqrt{L_3 \cdot C_1}}$	VCC	1.2
9	OSC	Controlling oscillation current at the terminal of FB	-K	_
10	GND	_	_	0

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Application Note

1. PW SW

It is necessary to connect an external pull-down resistor with the terminal PW SW (pin 6), in case that this IC is turned on due to external noise etc.

2. Designing of coil

This IC has the output voltage by means of boosting the oscillation voltage, derived from Hartley type oscillator circuit and of voltage–double rectifier with C₃, D₁ and D₂.

(1) Designing of oscillation frequency

$$f_{OSC} = \frac{1}{2\pi \sqrt{L_3 \cdot C_2}}$$

(2) Coil turns can be designed as following:

$$V_{\text{osc}}(p-p) = 2 \left(V_{\text{CC}}(min) - V_{\text{CE1}}(sat) \right)$$

$$n = \frac{n3}{n2} \ \dot{=} \ \frac{V_O}{V_{OSC(p-p)}}$$

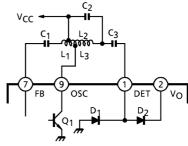


Fig.1 Oscillator and Voltage-Double

(Note) V_{CC (min)}: Minimum of supply voltage designed by a equipment

 $V_{CE1 (sat)}$: Saturation voltage of Q_1 n : Coil turns ratio (L_2 , L_3) V_O : Output voltage ($V_O = 14.3V$)

The turn of L_1 is designed, so as to make the terminal of FB be about $200 \sim 300 \text{mV}_{p-p}$ through C_1 . The turn of L_1 should be small, and the capacitance of C_1 and Q_0 of coil should be large, for the oscillation start at turning power on.

(3) Allowance is advisable for coil design of n, Q₀. However, spurious radiation can be reduced, in case that the output current and n of coil don't make large.

3. Pattern diagram

The Fig.2 shows the oscillation loop. This pattern diagram should be small, because spurious radiation due to the oscillation is reduced.

The Fig.3 shows the rectifier loop. This pattern diagram should be the small, because spurious radiation due to the switching rectifier is reduced. The two loops should be isolated from other DC lines.

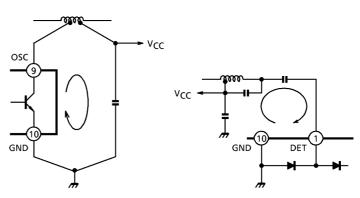


Fig.2 Oscillation Loop

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Fig.3 Rectifier Loop

4. Output current

Total output current (IO and ICTL) should not be smaller than 30µA, because this IC start blocking oscillation etc. Note that this condition will change according to coil setting etc.

5. Terminal CF

Any external parts should not be connected with this terminal, because this IC doesn't operate normally.

6. ICTL

ICTL can be controlled by RCTL resistor between pin 4 and GND, note that ICTL should be set to 180µA or smaller (see Fig.4).

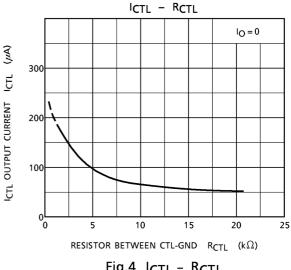


Fig.4 ICTL - RCTL

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5	V
Output voltage	Vo	18	V
Constant current source circuit output current	I _{CTL}	5	mA
Power dissipation (Note	P _D	300	mW
Operating temperature	T _{opr}	-25~75	°C
Storage temperature	T _{stg}	-55~150)

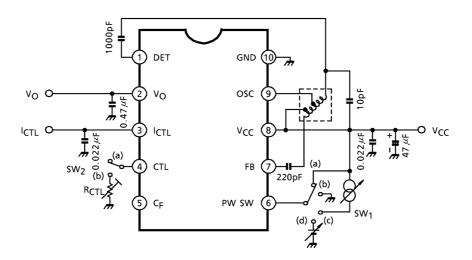
(Note) Derated above Ta = 25°C in the proportion of 2.4mW.

Electrical Characteristics

Unless Otherwise Specified: V_{CC} = 1.2V, Ta = 25°C, f_{osc} = 3MHz, I_O = 30 μ A, SW₁: a, SW₂: a

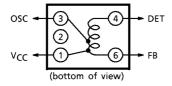
Characteristic	Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
Supply current	I _{CC1}	_	PW OFF, SW ₁ : b	_	_	5	μA
Зирріу сипепі	I _{CC2}	_		_	2.1	3	mA
Boosted output voltage	Vo	_		13.5	14.3	15.1	V
V _O supply voltage fluctuation	ΔV _O	_	V_{CC} = 4V \rightarrow 0.9V	-20	0	+20	mV
V _O maximum output current	I _{O (MAX)}	_	ΔV_{O} = 50mV, with respect to standard, I _{CTL} = 30 μ A	180	300	_	μA
V _O ambient temperature coefficient	V _O / T	_		_	+1.2	_	mV / °C
Constant current source output current	I _{CTL}	_	I_{O} = 0, SW ₂ : b (R _{CTL} = 4.7kΩ)	80	100	120	μA
I _{CTL} maximum current	I _{CTL} (MAX)	_	I_O = 0, SW ₂ : b, (adjust R _{CTL}) ΔV_O = 50mV, with respect to standard, I _{CTL} = 30 μ A	_	270	_	μА
Power switch on current	I ₆	_	V _{CC} =0.9V, V _O ≥ 13V, SW ₁ : c	5	_	_	μA
Power switch off voltage	V ₆	_	V_{CC} =0.9V, $V_{O} \le 3.5$ V, SW_{1} : d	0	_	0.3	V

Test Circuit



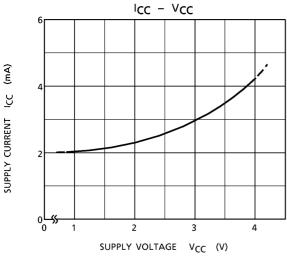
Coil Data (test circuit)

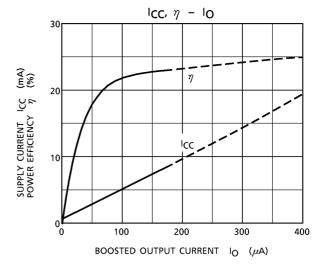
Test	L (µH)	Q		Turn		Wire	Reference
Frequency	uency 4-6		6–1	1–3	3–4	(mmø)	reletete
796kHz	152	25	$2\frac{1}{2}$	8	$89\frac{1}{2}$	0.04UEW	SUMIDA ELECTRIC & Co.,Ltd. 5201–018

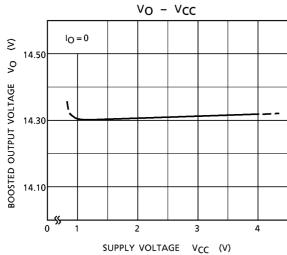


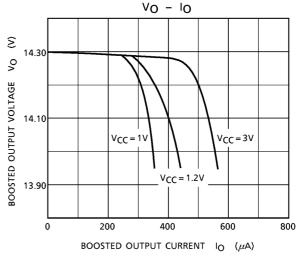
Characteristic Curves

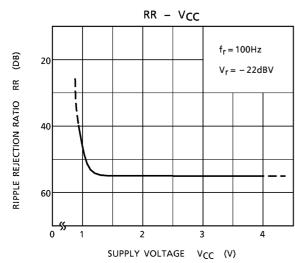
Unless Otherwise Specified: $V_{CC} = 1.2V$, $I_{O} = 30\mu A$, $Ta = 25^{\circ}C$, $f_{osc} = 3MHz$

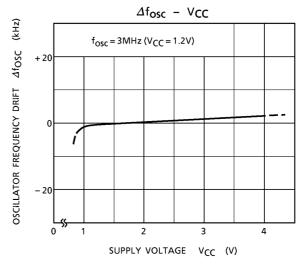




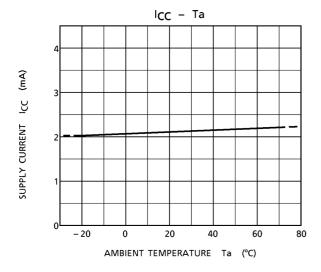


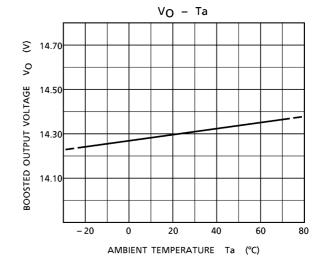


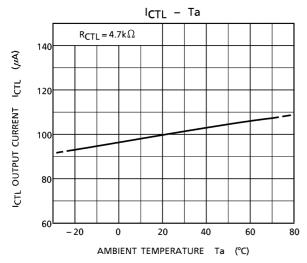


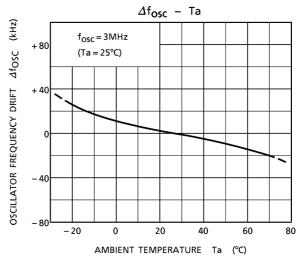


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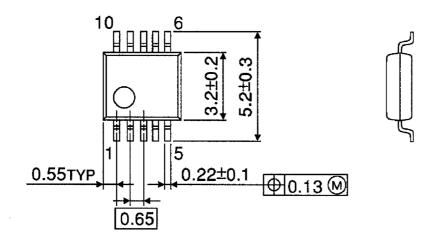


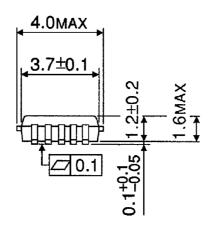
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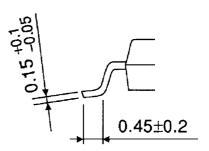
Package Dimensions

SSOP10-P-0.65

Unit: mm







Weight: 0.04g (typ.)

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